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APPLICANT J. Dennis Keller et al.				FILING DATE July 17, 1998			
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U.S. PATENT DOCUMENTS							
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						Yes	No
	AL						
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OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, Etc.)							
ME	AR		H. Shirai, et al., A 0.54 $\mu$ m * Self-Aligned, HSG Floating Gate Cell (SAHF Cell) for 256Mbit Flash Memories, 1995 IEEE pp27.1.1-27.1.4				
AR	AS		Yosiaki S. Hisamune et al, A High Capacitive-Coupling Ratio (HICR) Cell for 3 V-Only 64 Mbit and Future Flash Memories, 1993 IEEE pp2.3.1-2.3.4				
	AT						
EXAMINER		Michelle Estrada			DATE CONSIDERED		
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